



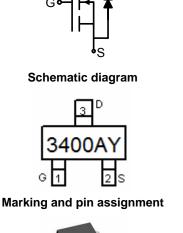
NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3400AY uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

- V_{DS} = 30V,I_D = 5.8A
 - $R_{DS(ON)} < 55m\Omega @ V_{GS}=2.5V$ $R_{DS(ON)} < 42m\Omega @ V_{GS}=4.5V$
 - $R_{DS(ON)} < 40m\Omega @ V_{GS} = 10V$
- High power and current handing capability
- Lead free product is acquired
- Surface mount package
- PWM applications
- Load switch
- Power management





SOT23-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3400AY	NCE3400AY	SOT23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I _D	5.8	А
Drain Current-Pulsed (Note 1)	I _{DM}	30	A
Maximum Power Dissipation	PD	1.4	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

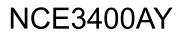
Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	89	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30	33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	-	1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	0.7	0.9	1.4	V
	R _{DS(ON)}	V_{GS} =2.5V, I_{D} =4A	-	41	55	mΩ
Drain-Source On-State Resistance		V_{GS} =4.5V, I_{D} =5A	-	28	42	mΩ
		V_{GS} =10V, I _D =5.8A	-	24	40	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =5A	10	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	V _{DS} =15V,V _{GS} =0V,	-	825	-	PF
Output Capacitance	Coss	F=1.0MHz	-	100	-	PF
Reverse Transfer Capacitance	C _{rss}	F = 1.000112	-	78	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	3.3	-	nS
Turn-on Rise Time	tr	V_{DD} =15V, R _L =2.7 Ω	-	4.8	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =3 Ω	-	26	-	nS
Turn-Off Fall Time	t _f		-	4	-	nS
Total Gate Charge	Qg		-	10	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V,I _D =5.8A, V _{GS} =4.5V	-	1.6	-	nC
Gate-Drain Charge	Q _{gd}	v _{GS} -4.3v	-	3.1	-	nC
Drain-Source Diode Characteristics						•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =5.8A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	5.8	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, t \leq 10 sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production





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NCE3400AY

Typical Electrical and Thermal Characteristics

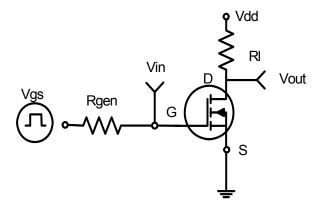
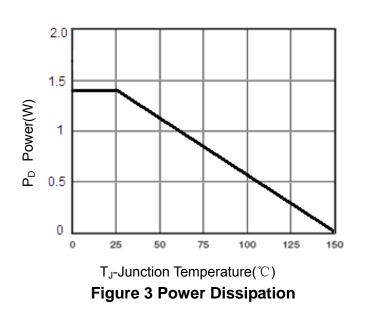
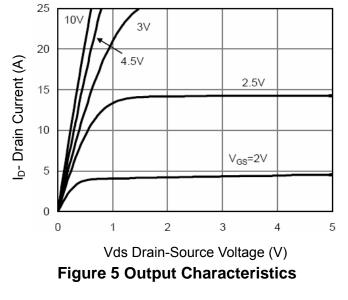


Figure 1:Switching Test Circuit





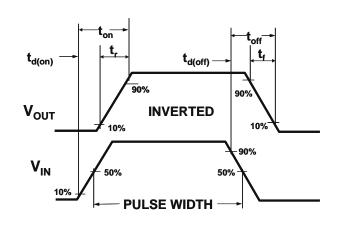
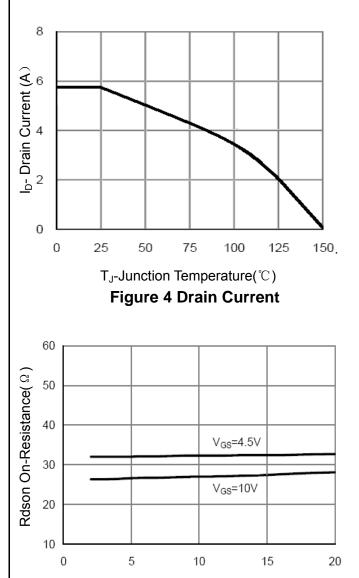


Figure 2:Switching Waveforms



I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance



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Pb Free Product

NCE3400AY

V_{GS}=10∨

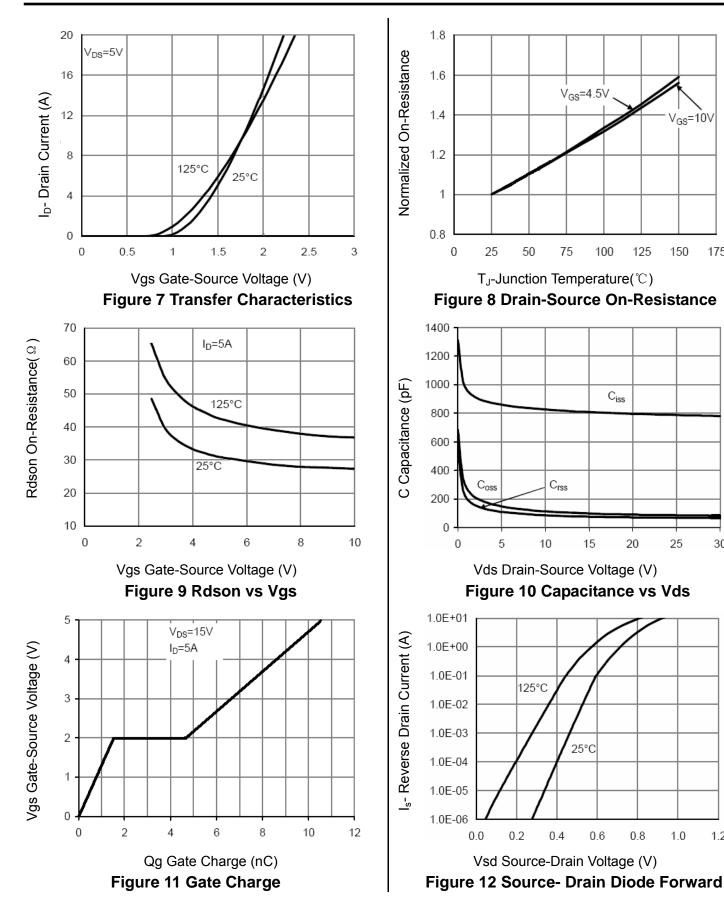
150

25

1.0

30

175



1.2





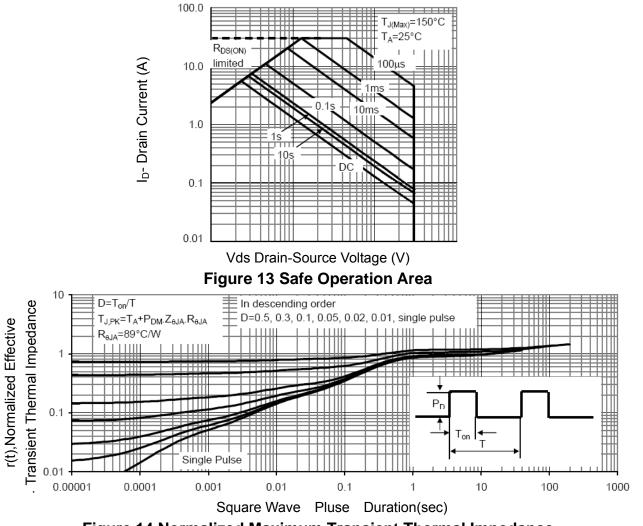
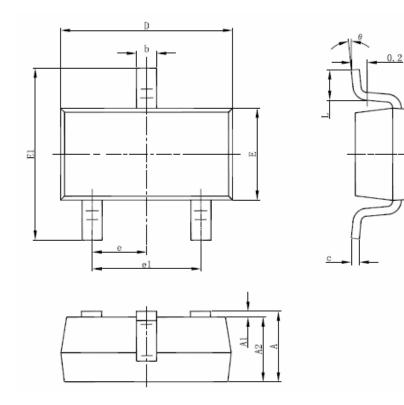


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23-3L Package Information



Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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